

International
IOR Rectifier

MBR350
MBR360

SCHOTTKY RECTIFIER

3.0 Amp

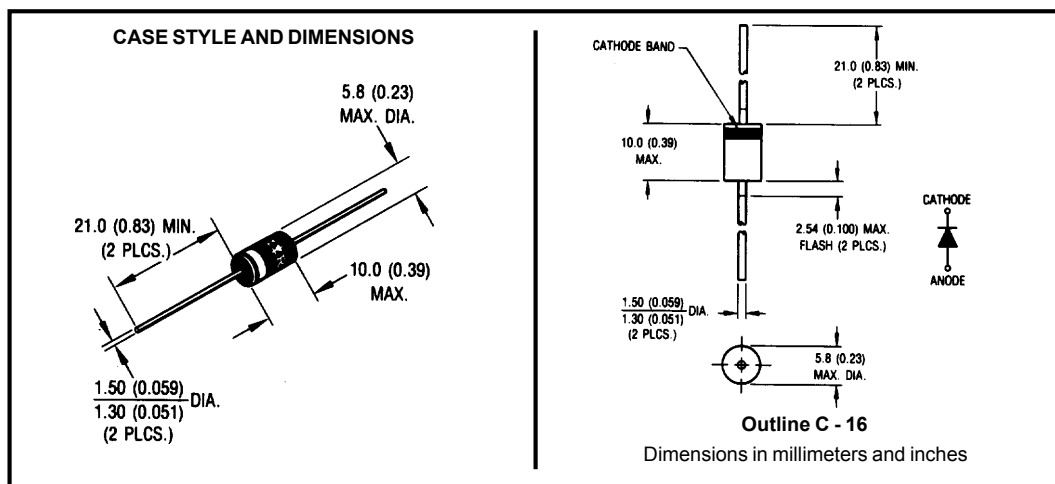
Major Ratings and Characteristics

Characteristics	MBR350 MBR360	Units
$I_{F(AV)}$ Rectangular waveform	3.0	A
V_{RRM}	50/60	V
I_{FSM} @ $t_p = 5 \mu s$ sine	460	A
V_F @3Apk, $T_J = 25^\circ C$	0.73	V
T_J	-40 to 150	$^\circ C$

Description/Features

The MBR350, MBR360 axial leaded Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

- Low profile, axial leaded outline
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



Voltage Ratings

Part number	MBR350	MBR360
V_R Max. DC Reverse Voltage (V)	50	60
V_{RWM} Max. Working Peak Reverse Voltage (V)		

Absolute Maximum Ratings

Parameters	Value	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current * See Fig. 4	3.0	A	50% duty cycle @ $T_L = 50^\circ\text{C}$, rectangular waveform
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current * See Fig. 6	460	A	5 μs Sine or 3 μs Rect. pulse
	80		10ms Sine or 6ms Rect. pulse
E_{AS} Non-Repetitive Avalanche Energy	6.0	mJ	$T_J = 25^\circ\text{C}$, $I_{AS} = 1$ Amps, $L = 10$ mH
I_{AR} Repetitive Avalanche Current	0.4	A	Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. $V_A = 1.5 \times V_R$ typical

Electrical Specifications

Parameters	Value	Units	Conditions
V_{FM} Max. Forward Voltage Drop * See Fig. 1 (1)	0.58	V	@ 1.0A
	0.73	V	@ 3.0A
	1.06	V	@ 9.4A
	0.49	V	@ 1.0A
	0.64	V	@ 3.0A
	0.89	V	@ 9.4A
I_{RM} Max. Reverse Leakage Current * See Fig. 2 (1)	0.6	mA	$T_J = 25^\circ\text{C}$
	8	mA	$T_J = 100^\circ\text{C}$
	15	mA	$T_J = 125^\circ\text{C}$
C_T Typical Junction Capacitance	190	pF	$V_R = 5V_{DC}$ (test signal range 100Khz to 1Mhz) 25°C
L_S Typical Series Inductance	9.0	nH	Measured lead to lead 5mm from package body
dv/dt Max. Voltage Rate of Change	10000	V/ μs	(Rated V_R)

(1) Pulse Width < 300 μs , Duty Cycle < 2%

Thermal-Mechanical Specifications

Parameters	Value	Units	Conditions
T_J Max. Junction Temperature Range (*)	-40 to 150	$^\circ\text{C}$	
T_{stg} Max. Storage Temperature Range	-40 to 150	$^\circ\text{C}$	
R_{thJL} Typical Thermal Resistance Junction to Lead (**)	30	$^\circ\text{C}/\text{W}$	DC Operation (* See Fig. 4)
wt Approximate Weight	1.2(0.042)	g(oz.)	
Case Style	C-16		

(*) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{th}(j-a)}$ thermal runaway condition for a diode on its own heatsink

(**) Mounted 1 inch square PCB, thermal probe connected to lead 2mm from package

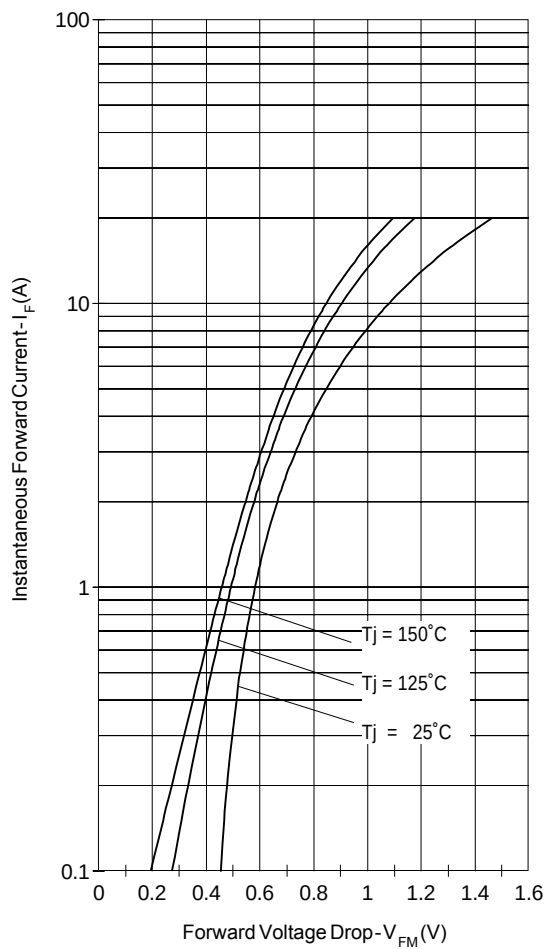


Fig. 1 - Max. Forward Voltage Drop Characteristics

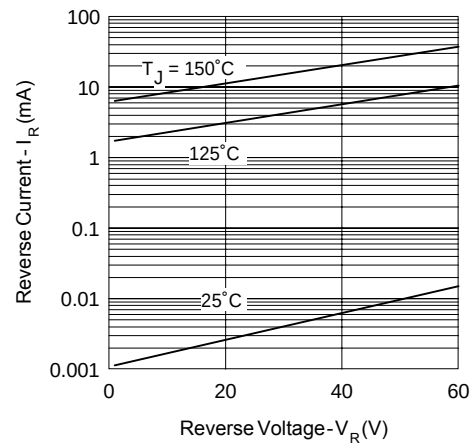


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage

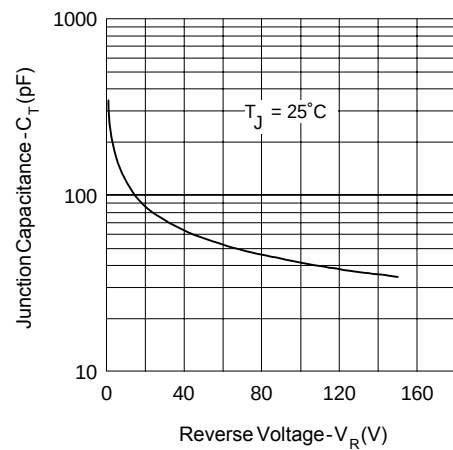


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

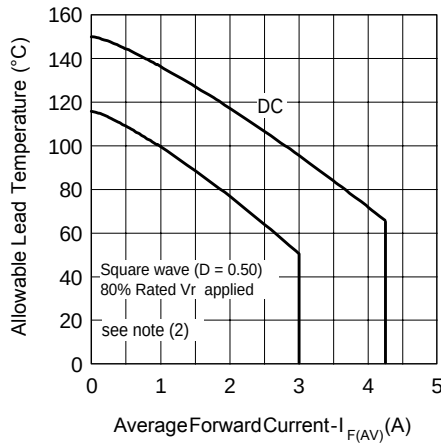


Fig. 4 - Max. Allowable Lead Temperature Vs. Average Forward Current

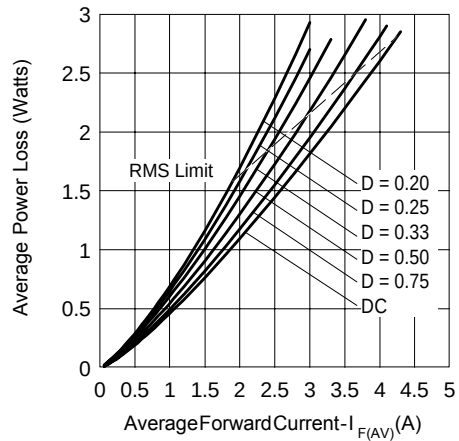


Fig. 5 - Forward Power Loss Characteristics

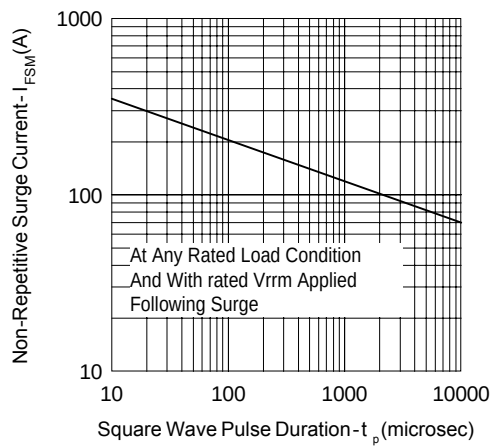


Fig. 6 - Max. Non-Repetitive Surge Current

(2) Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$;

P_d = Forward Power Loss = $I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);

$P_{d_{REV}}$ = Inverse Power Loss = $V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1} = 80\% \text{ rated } V_R$

Ordering Information Table

Device Code			
1	2	3	4
MBR	3	60	TR
1	40 = 40V 60 = 60V		
2	Current Rating: 3 = 3A		
3	Voltage Rating		
4	TR = Tape & Reel package (1200 pcs) = Box package (500 pcs)		

Data and specifications subject to change without notice.
 This product has been designed and qualified for Industrial Level.
 Qualification Standards can be found on IR's Web site.

International
IR Rectifier

IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105
 TAC Fax: (310) 252-7309
 Visit us at www.irf.com for sales contact information. 03/02